Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.050 inches

Mounting Facility Quantity:

1

Electrode Internally-electrically Connected To Case:

Cathode

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

1.057 inches

Thread Size:

0.375 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 reverse voltage, peak

Current Rating Per Characteristic:

25.00 milliamperes reverse current, dc

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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